



Technical Data Sheet

5mm Infrared LED , T-1 3/4

IR383

Features

- High reliability
- High radiant intensity
- Peak wavelength $\lambda_p=940\text{nm}$
- 2.54mm Lead spacing
- Low forward voltage
- Pb free
- The product itself will remain within RoHS compliant version.

Descriptions

- EVERLIGHT'S Infrared Emitting Diode(IR383) is a high intensity diode , molded in a blue transparent plastic package.
- The device is spectrally matched with phototransistor , photodiode and infrared receiver module.



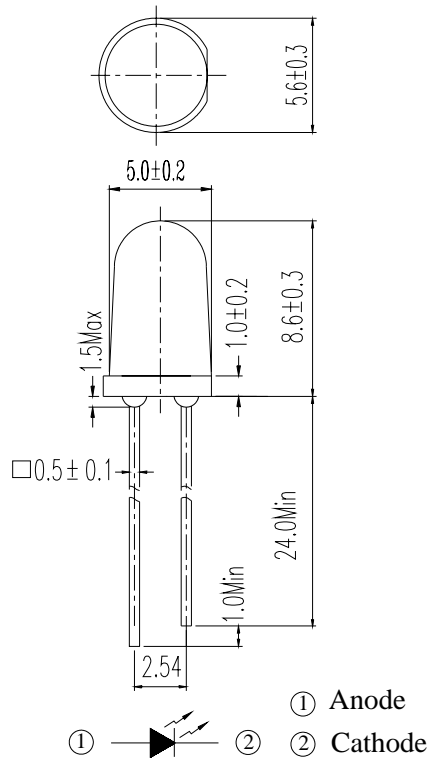
Applications

- Free air transmission system
- Infrared remote control units with high power requirement
- Smoke detector
- Infrared applied system

Device Selection Guide

| LED Part No. | Chip | Lens Color |
|--------------|----------|------------|
| | Material | |
| IR | GaAlAs | Blue |

Package Dimensions



- Notes:** 1.All dimensions are in millimeters
2.Tolerances unless dimensions $\pm 0.25\text{mm}$

Absolute Maximum Ratings ($T_a=25^\circ\text{C}$)

| Parameter | Symbol | Rating | Units |
|--|-----------|-----------|------------------|
| Continuous Forward Current | I_F | 100 | mA |
| Peak Forward Current *1 | I_{FP} | 1.0 | A |
| Reverse Voltage | V_R | 5 | V |
| Operating Temperature | T_{opr} | -40 ~ +85 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | -40 ~ +85 | $^\circ\text{C}$ |
| Soldering Temperature*2 | T_{sol} | 260 | $^\circ\text{C}$ |
| Power Dissipation at(or below) 25 $^\circ\text{C}$ Free Air Temperature | P_d | 150 | mW |

- Notes:** *1: I_{FP} Conditions--Pulse Width $\leq 100 \mu\text{s}$ and Duty $\leq 1\%$.
*2:Soldering time ≤ 5 seconds.

Electro-Optical Characteristics (Ta=25°C)

| Parameter | Symbol | Condition | Min. | Typ. | Max. | Units |
|--------------------|----------------|--|------|------|------|-------|
| Radiant Intensity | Ee | I _F =20mA | 7.8 | 20 | -- | mW/sr |
| | | I _F =100mA Pulse Width ≤ 100 μs ,Duty ≤ 1% | -- | 80 | -- | |
| | | I _F =1A Pulse Width ≤ 100 μs ,Duty ≤ 1%. | -- | 800 | -- | |
| Peak Wavelength | λ _p | I _F =20mA | -- | 940 | -- | nm |
| Spectral Bandwidth | Δλ | I _F =20mA | -- | 45 | -- | nm |
| Forward Voltage | V _F | I _F =20mA | | 1.2 | 1.5 | V |
| | | I _F =100mA Pulse Width ≤ 100 μs ,Duty ≤ 1% | -- | 1.4 | 1.8 | |
| | | I _F =1A Pulse Width ≤ 100 μs ,Duty ≤ 1%. | -- | 2.6 | 4.0 | |
| Reverse Current | I _R | V _R =5V | -- | -- | 10 | μA |
| View Angle | 2θ 1/2 | I _F =20mA | -- | 20 | -- | deg |

Rank

 Condition : I_F=20mA

Unit : mW/sr

| Bin Number | M | N | P | Q |
|------------|------|------|------|------|
| Min | 7.80 | 11.0 | 15.0 | 21.0 |
| Max | 12.5 | 17.6 | 24.0 | 34.0 |

Typical Electro-Optical Characteristics Curves

Fig.1 Forward Current vs. Ambient Temperature

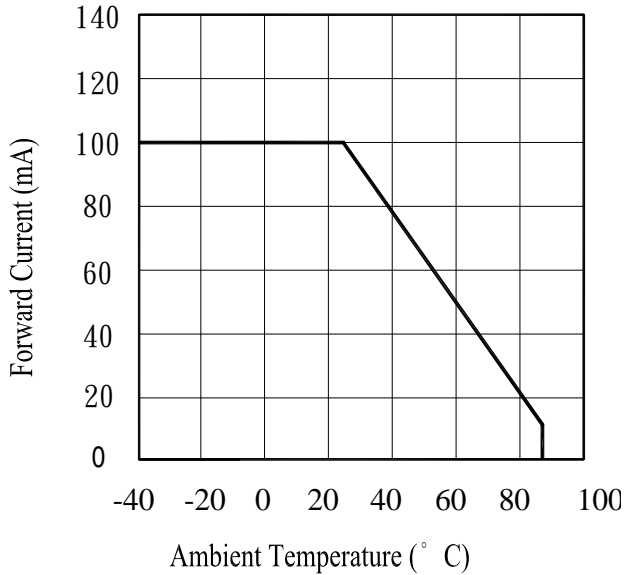


Fig.2 Spectral Distribution

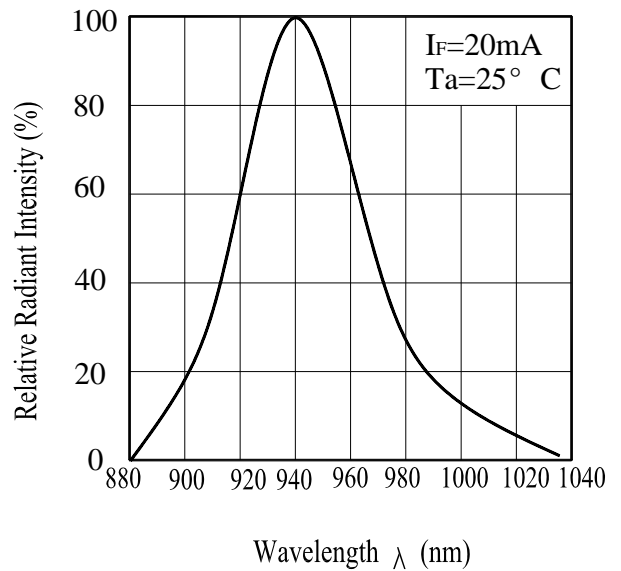


Fig.3 Peak Emission Wavelength vs. Ambient Temperature

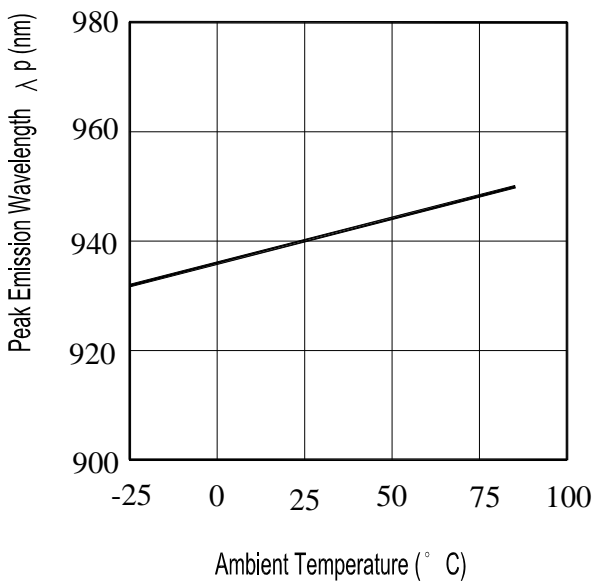
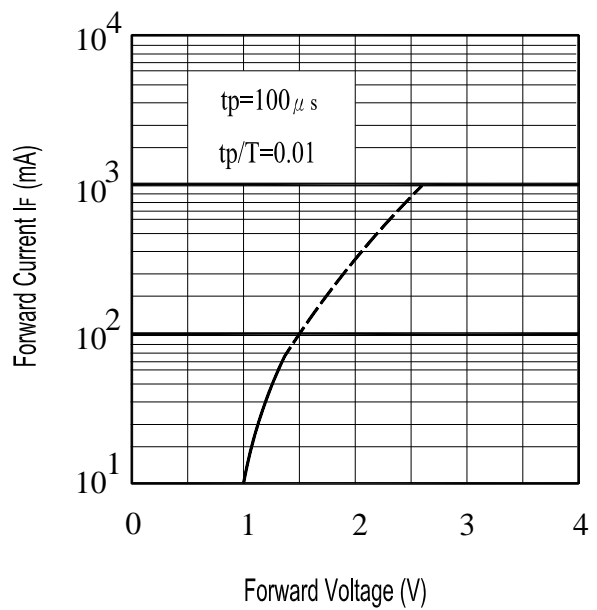


Fig.4 Forward Current vs. Forward Voltage



Typical Electro-Optical Characteristics Curves

Fig.5 Radiant Intensity vs. Forward Current

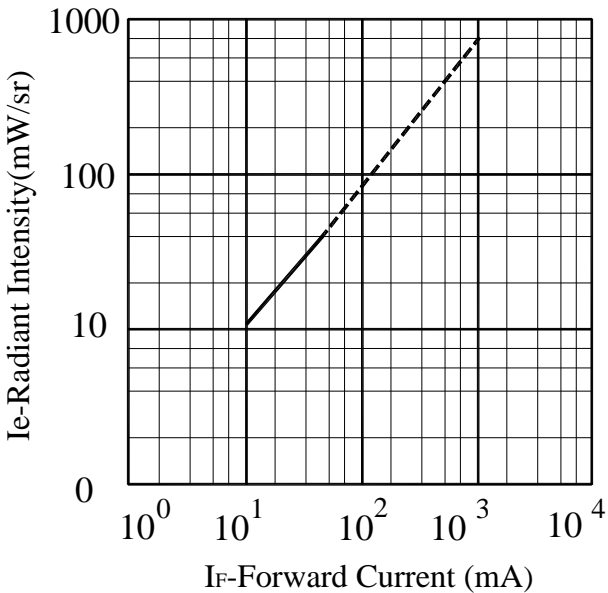


Fig.6 Relative Radiant Intensity vs. Angular Displacement

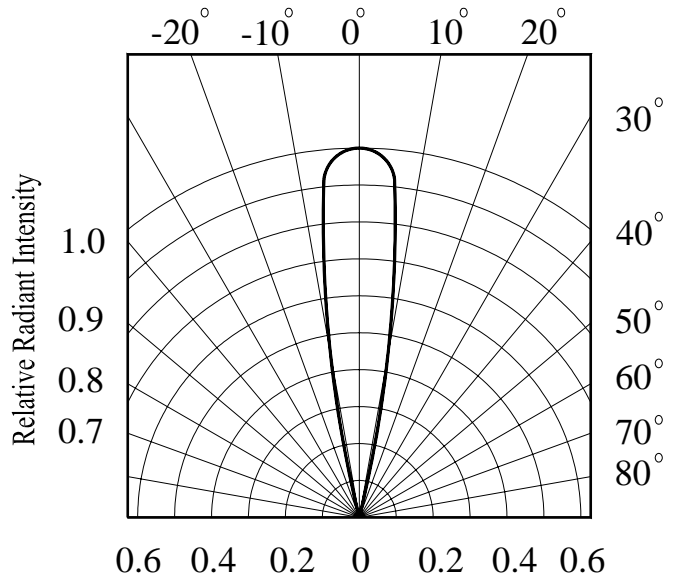


Fig.7 Radiant Intensity vs. Ambient Temperature(°C)

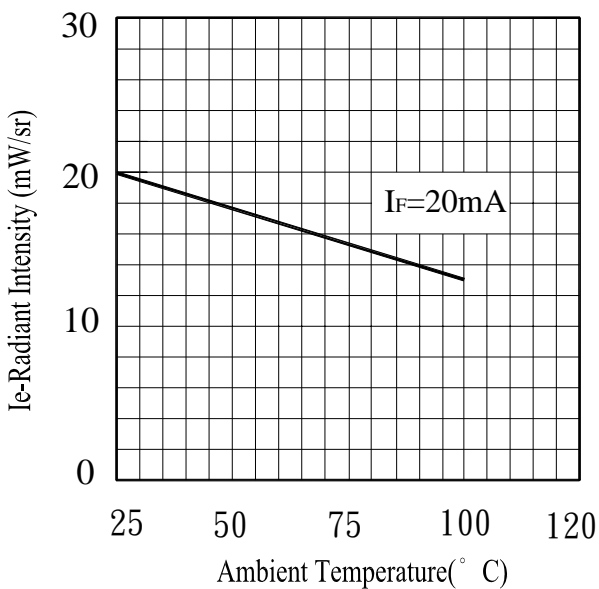
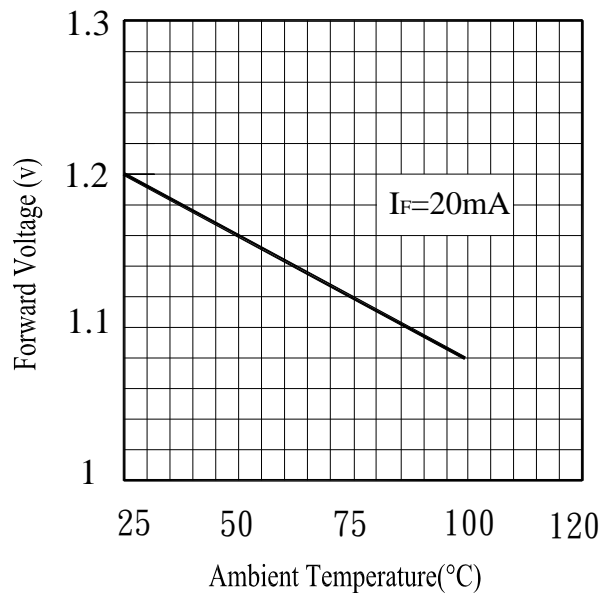


Fig.8 Forward Voltage vs. Ambient Temperature(°C)



Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

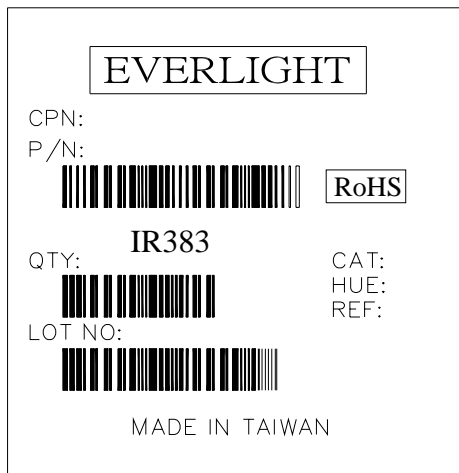
LTPD : 10%

| NO. | Item | Test Conditions | Test Hours/ Cycles | Sample Sizes | Failure Judgement Criteria | Ac/Re |
|-----|------------------------------------|--|-----------------------|-----------------|---|-------|
| 1 | Solder Heat | TEMP. : 260°C±5°C | 10secs | 22pcs | $I_R \geq U \times 2$ $E_e \leq L \times 0.8$ $V_F \geq U \times 1.2$ U : Upper Specification Limit L : Lower Specification Limit | 0/1 |
| 2 | Temperature Cycle | H : +100°C 15mins ↑ 5mins ↓ L : -40°C 15mins | 300Cycles | 22pcs | | 0/1 |
| 3 | Thermal Shock | H : +100°C 5mins ↑ 10secs ↓ L : -10°C 5mins | 300Cycles | 22pcs | | 0/1 |
| 4 | High Temperature Storage | TEMP. : +100°C | 1000hrs | 22pcs | | 0/1 |
| 5 | Low Temperature Storage | TEMP. : -40°C | 1000hrs | 22pcs | | 0/1 |
| 6 | DC Operating Life | $I_F=20mA$ | 1000hrs | 22pcs | | 0/1 |
| 7 | High Temperature/ High Humidity | 85°C / 85% R.H | 1000hrs | 22pcs | | 0/1 |

Packing Quantity Specification

1.500PCS/1Bag , 5Bags/1Box

2.10Boxes/1Carton

Label Form Specification

CPN: Customer's Production Number

P/N : Production Number

QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

MADE IN TAIWAN: Production Place

Notes

1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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